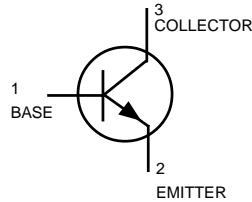


# General Purpose Transistors

NPN Silicon

**BC847BRLT1**



CASE 318-07, STYLE 6  
SOT-23 (TO-236AB)

## MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CEO}$	50	V
Collector-Base Voltage	$V_{CBO}$	60	V
Emitter-Base Voltage	$V_{EBO}$	7.0	V
Collector Current — Continuous	$I_C$	150	mAdc
Collector power dissipation	$P_c$	0.2	W
Junction temperature	$T_j$	150	°C
Storage temperature	$T_{stg}$	-55 ~ +150	°C

## DEVICE MARKING

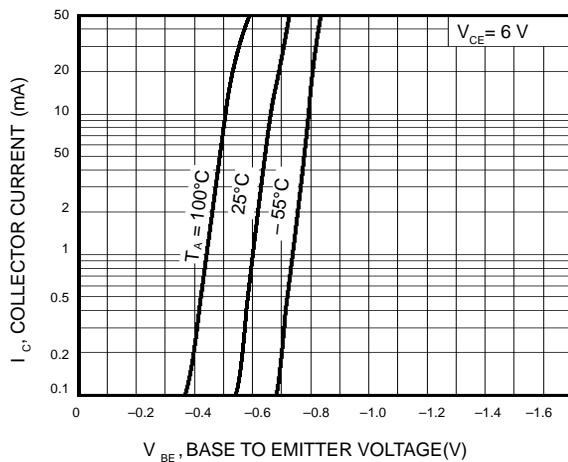
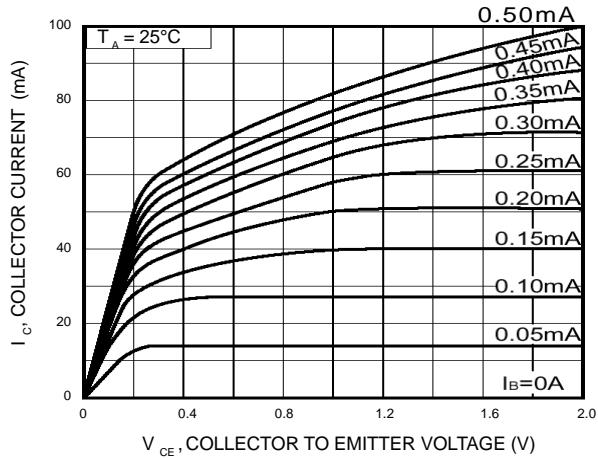
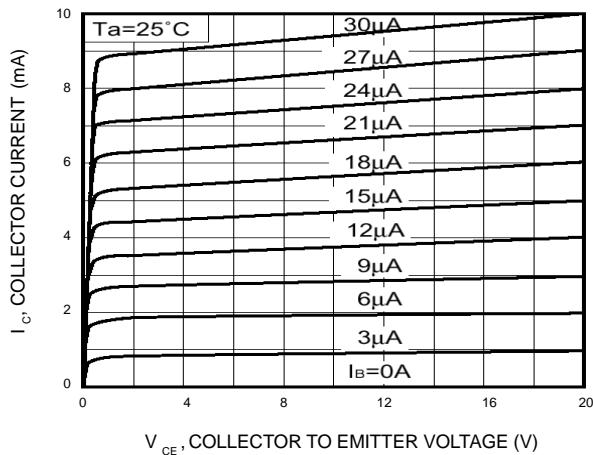
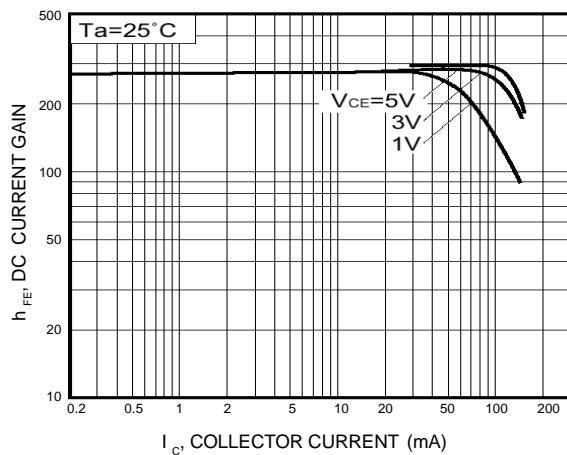
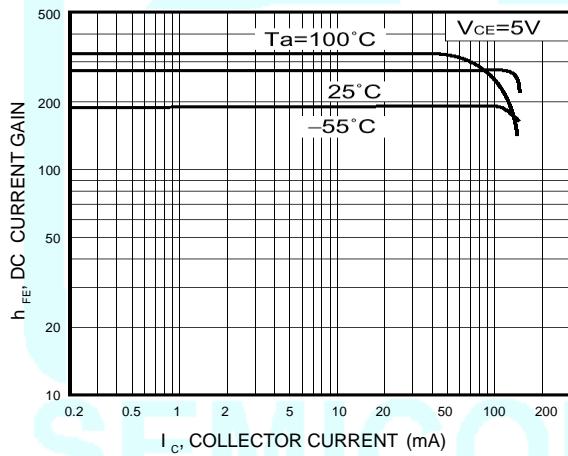
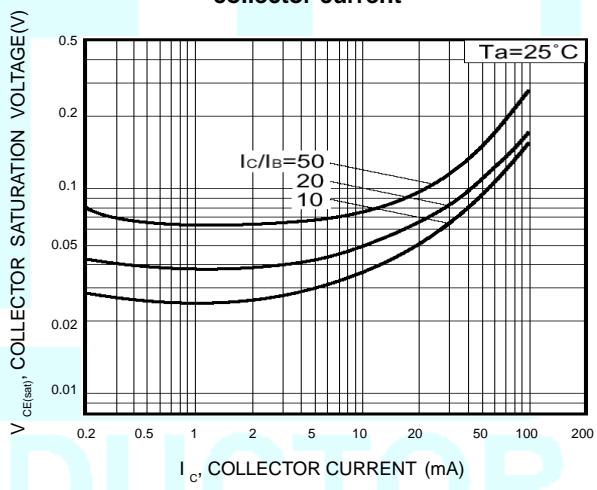
BC847BRLT1 =G1F

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
Collector-Emitter Breakdown Voltage ( $I_C = 1 \text{ mA}$ )	$V_{(BR)CEO}$	50	—	—	V
Emitter-Base Breakdown Voltage ( $I_E = 50 \mu\text{A}$ )	$V_{(BR)EBO}$	7	—	—	V
Collector-Base Breakdown Voltage ( $I_C = 50 \mu\text{A}$ )	$V_{(BR)CBO}$	60	—	—	V
Collector Cutoff Current ( $V_{CB} = 60 \text{ V}$ )	$I_{CBO}$	—	—	0.1	$\mu\text{A}$
Emitter cutoff current ( $V_{EB} = 7 \text{ V}$ )	$I_{EBO}$	—	—	0.1	$\mu\text{A}$
Collector-emitter saturation voltage ( $I_C/I_B = 50 \text{ mA} / 5 \text{ mA}$ )	$V_{CE(sat)}$	—	—	0.4	V
DC current transfer ratio ( $V_{CE} = 6 \text{ V}, I_C = 1 \text{ mA}$ )	$h_{FE}$	120	—	560	—
Transition frequency ( $V_{CE} = 12 \text{ V}, I_E = -2 \text{ mA}, f = 30 \text{ MHz}$ )	$f_T$	—	180	—	MHz
Output capacitance ( $V_{CB} = 12 \text{ V}, I_E = 0 \text{ A}, f = 1 \text{ MHz}$ )	$C_{ob}$	—	2.0	3.5	pF

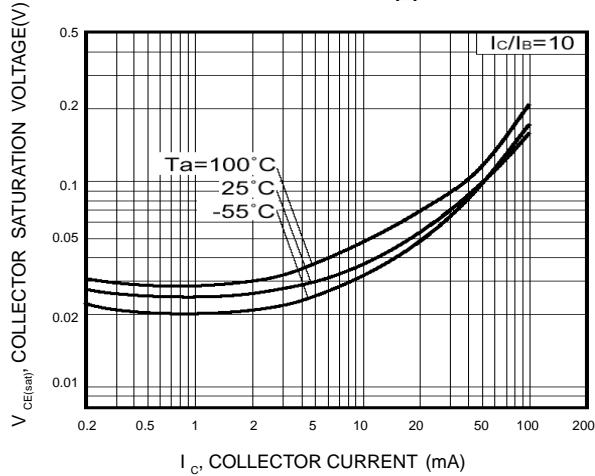
$h_{FE}$  values are classified as follows:

*	Q	R	S
hFE	120~270	180~390	270~560

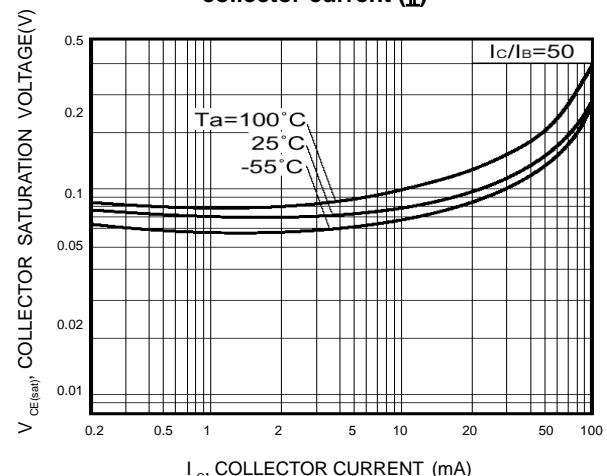
**Fig.1 Grounded emitter propagation characteristics**

**Fig.2 Grounded emitter output characteristics(I)**

**Fig.3 Grounded emitter output characteristics(II)**

**Fig.4 DC current gain vs. collector current (I)**

**Fig.5 DC current gain vs. collector current (II)**

**Fig.6 Collector-emitter saturation voltage vs. collector current**


**BC847BRLT1**

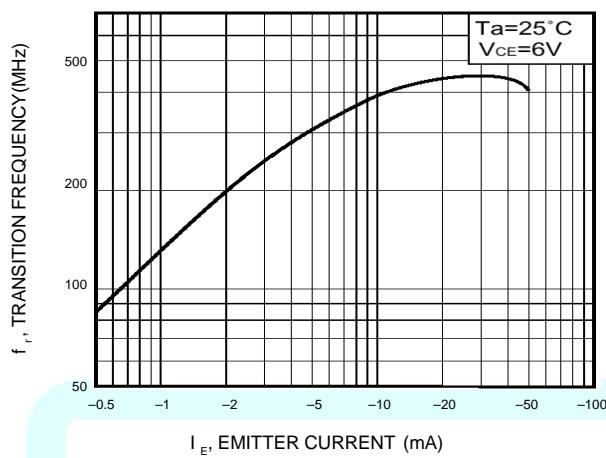
**Fig.7 Collector-emitter saturation voltage vs. collector current (I)**



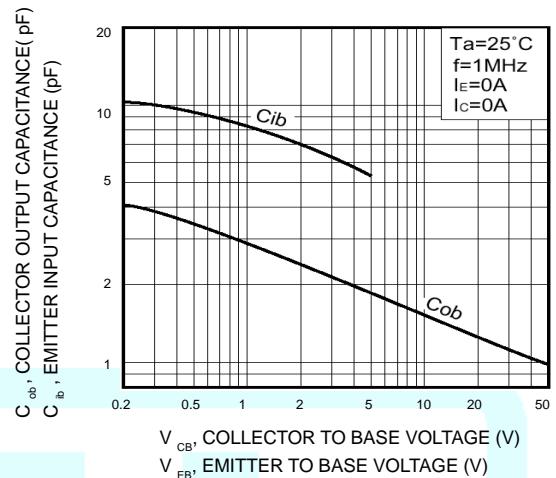
**Fig.8 Collector-emitter saturation voltage vs. collector current (II)**



**Fig.9 Gain bandwidth product vs. emitter current**



**Fig.10 Collector output capacitance vs. collector-base voltage  
Emitter inputcapacitance vs. emitter-base voltage**



**Fig.11 Base-collector time constant vs. emitter current**

